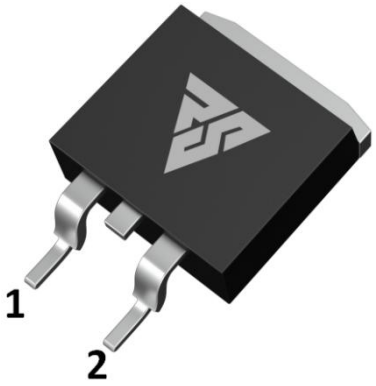
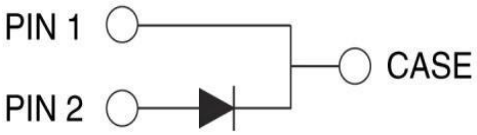
VRRM	IF (TC≤135℃)	QC
650V	9A	18nC





Applications:
- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Features:
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on VF
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits:
- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Ordering Information

Part Number	Package	Marking	Packing	Qty.
RSS06065S	TO-263	RSS06065S	Tape&reel	800 PCS

Maximum Ratings (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
VRRM	Repetitive Peak Reverse Voltage	650	V	TC = 25℃	
VRSM	Surge Peak Reverse Voltage	650	V	TC = 25℃	
VR	DC Blocking Voltage	650	V	TC = 25℃	
IF	Forward Current	20 9 6	A	TC ≤ 25℃ TC ≤ 135℃ TC ≤ 153℃	Fig. 3
IFSM	Non-Repetitive Forward Surge Current	66 57	A	TC = 25℃, tp = 10ms, Half Sine Wave TC = 110℃, tp = 10ms, Half Sine Wave	
IFRM	Repetitive Peak Forward Surge Current	60	A	TC = 25℃, tp = 10ms, Half Sine Wave	
Ptot	Power Dissipation	87	W	TC = 25℃	Fig. 4
TC	Maximum Case Temperature	153	℃		
TJ,TSTG	Operating Junction and Storage Temperature	-55 to17 5	℃		

Electrical Characteristics (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
VF	Forward Voltage	1.34 1.67	1.5 -	V	IF = 6A, TJ = 25℃ IF = 6A, TJ = 175℃	Fig.1
IR	Reverse Current	1.2 4.5	50 -	μA	VR = 650V, TJ = 25℃ VR = 650V, TJ = 175℃	Fig.2
C	Total Capacitance	261 35 33	/	pF	VR = 1V, TJ = 25℃, f = 1MHz VR = 200V, TJ = 25℃, f = 1MHz VR = 400V, TJ = 25℃, f = 1MHz	Fig.5
QC	Total Capacitive Charge	18	/	nC	VR =400V,	Fig.6
Ec	Capacitance Stored Energy	2.9		uJ	VR =400V,	Fig.7

Thermal Characteristics (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Typ.	Unit	Note
RθJC	Thermal Resistance from Junction to Case	1.73	℃/W	Fig.8

Typical Feature Curve

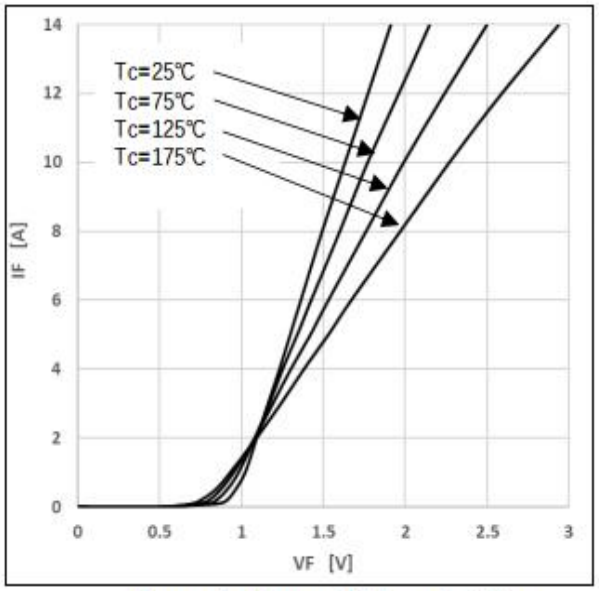


Figure 1 Forward Characteristics

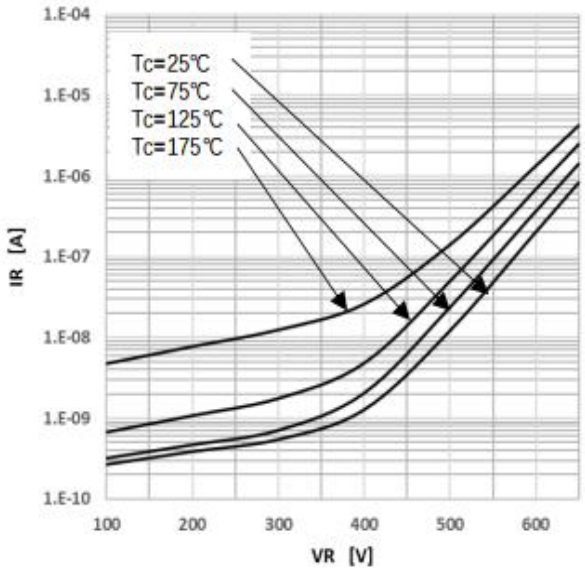


Figure 2 Reverse Characteristics

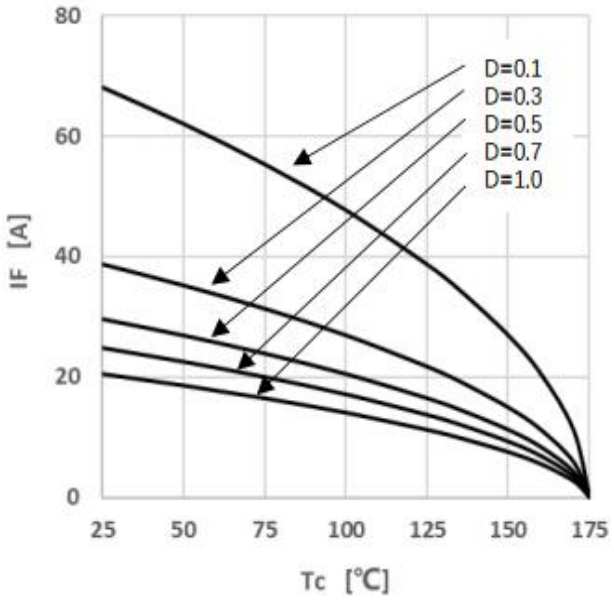


Figure 3 Peak Forward Current Derating

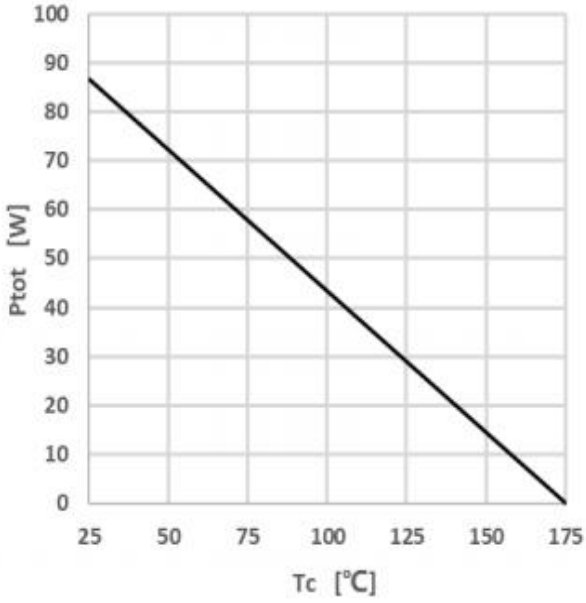


Figure 4 Power Dissipation

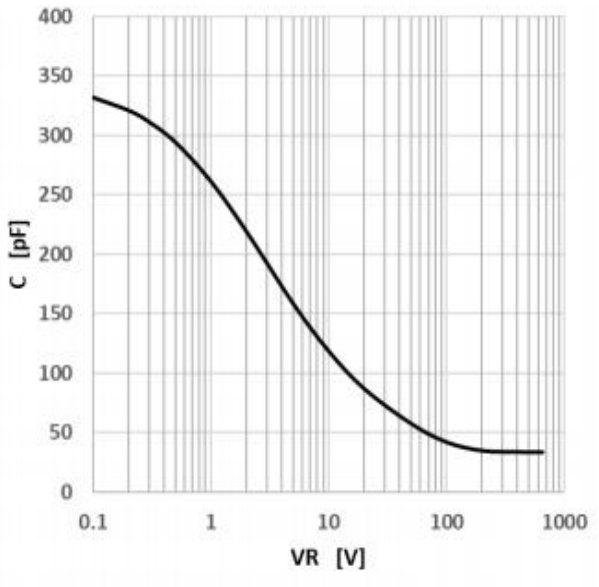


Figure 5 Capacitance vs. Reverse Voltage

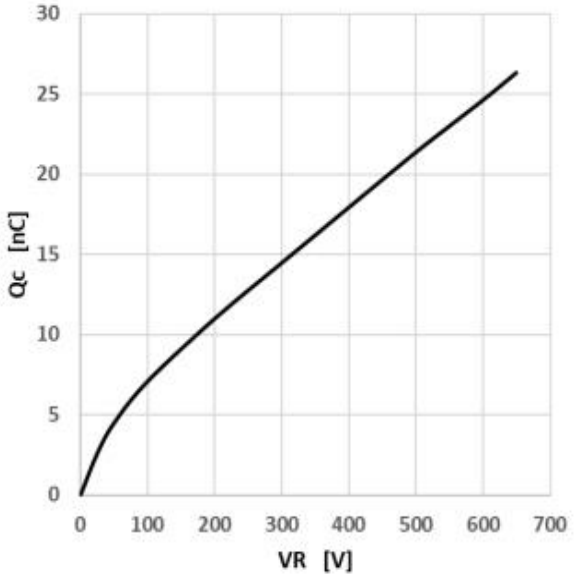


Figure 6 Capacitance Charge vs. Reverse Voltage

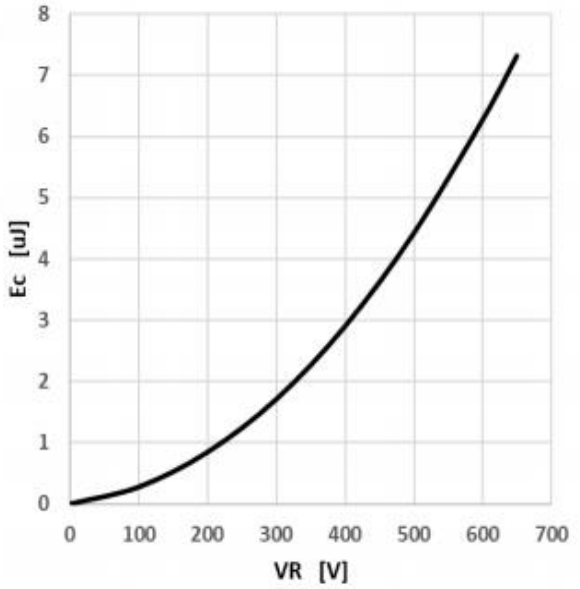


Figure 7 Capacitance Stored Energy

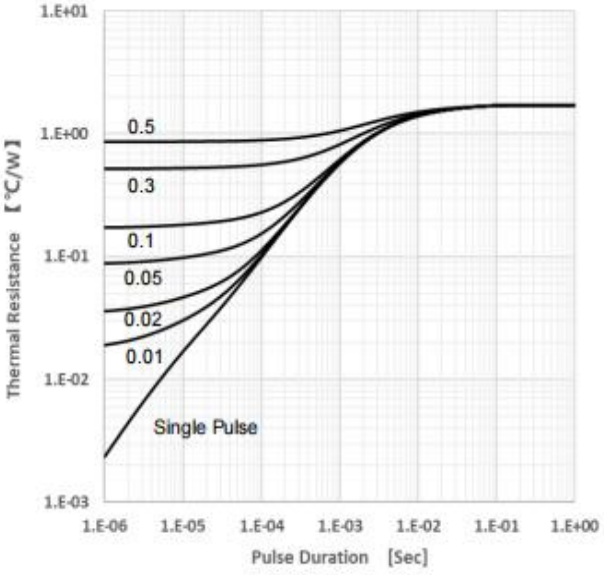
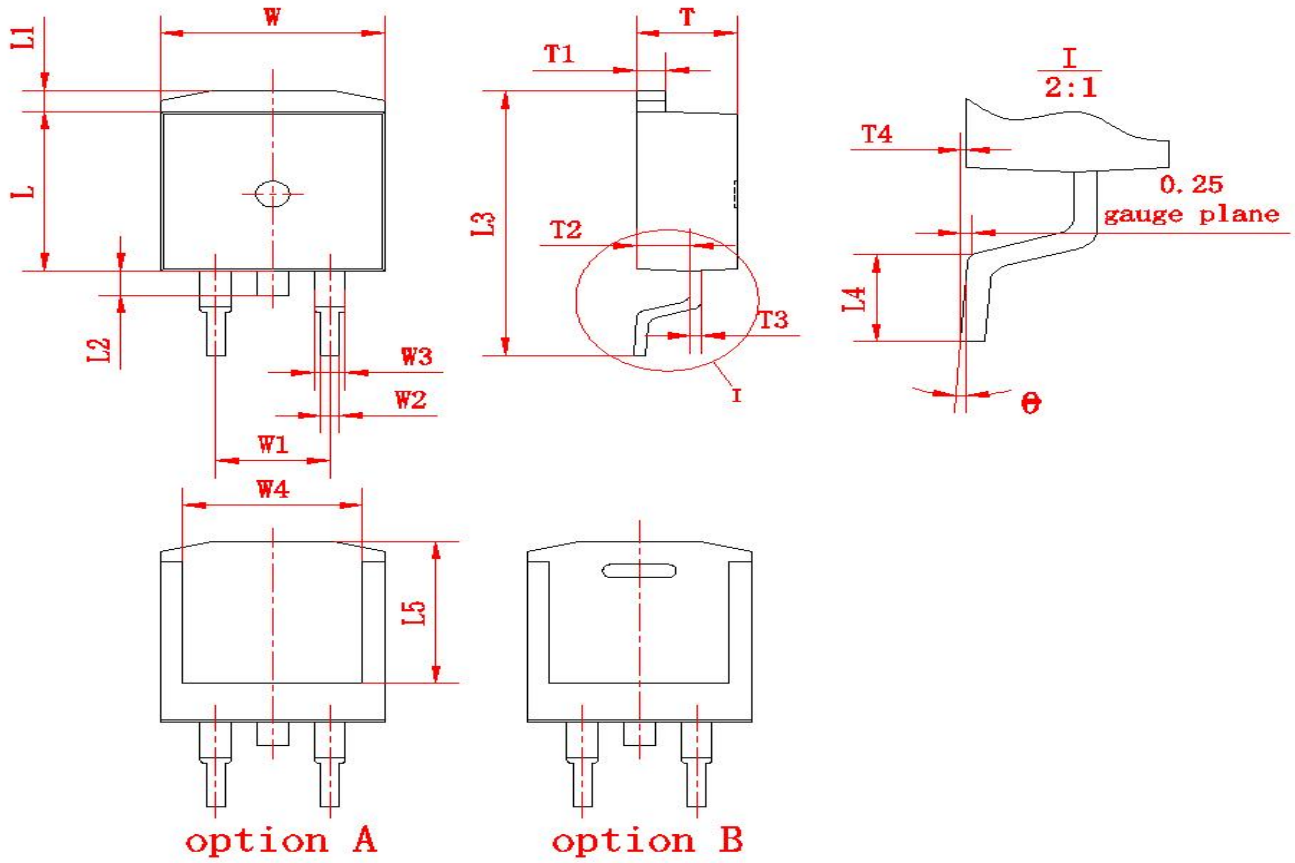


Figure 8 Transient Thermal Impedance

Package outline drawing(TO-263 Unit: mm)



（单位：mm）

符号	尺寸		符号	尺寸		符号	尺寸	
	Min	Max		Min	Max		Min	Max
W	9.80	10.20	L1	1.00	1.40	T1	1.20	1.40
W1	(5.08)		L2	1.20	1.60	T2	2.20	2.60
W2	0.70	0.95	L3	15.00	15.60	T3	0.45	0.65
W3	1.17	1.62	L4	2.20	2.80	T4	0	0.25
W4	(8.0)		L5	(8.2)		θ	0°	8°
L	9.00	9.40	T	4.30	4.70			

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c.whose failuer to when properly used in accordance with instructions for used provided in the laeling,can be reasonably expected to result in significant injury to the user.

2.A critical component is any component of a life support device or system whose failure to system whose failure to perform can be reasonably expected to cause the failure of the life support device or system,or to affect its safety or effectiveness.